



The Infinite Bandwidth Company™

# MIC4421/4422

## 9A-Peak Low-Side MOSFET Driver

### Bipolar/CMOS/DMOS Process

### General Description

MIC4421 and MIC4422 MOSFET drivers are rugged, efficient, and easy to use. The MIC4421 is an inverting driver, while the MIC4422 is a non-inverting driver.

Both versions are capable of 9A (peak) output and can drive the largest MOSFETs with an improved safe operating margin. The MIC4421/4422 accepts any logic input from 2.4V to  $V_S$  without external speed-up capacitors or resistor networks. Proprietary circuits allow the input to swing negative by as much as 5V without damaging the part. Additional circuits protect against damage from electrostatic discharge.

MIC4421/4422 drivers can replace three or more discrete components, reducing PCB area requirements, simplifying product design, and reducing assembly cost.

Modern Bipolar/CMOS/DMOS construction guarantees freedom from latch-up. The rail-to-rail swing capability of CMOS/DMOS insures adequate gate voltage to the MOSFET during power up/down sequencing. Since these devices are fabricated on a self-aligned process, they have very low crossover current, run cool, use little power, and are easy to drive.

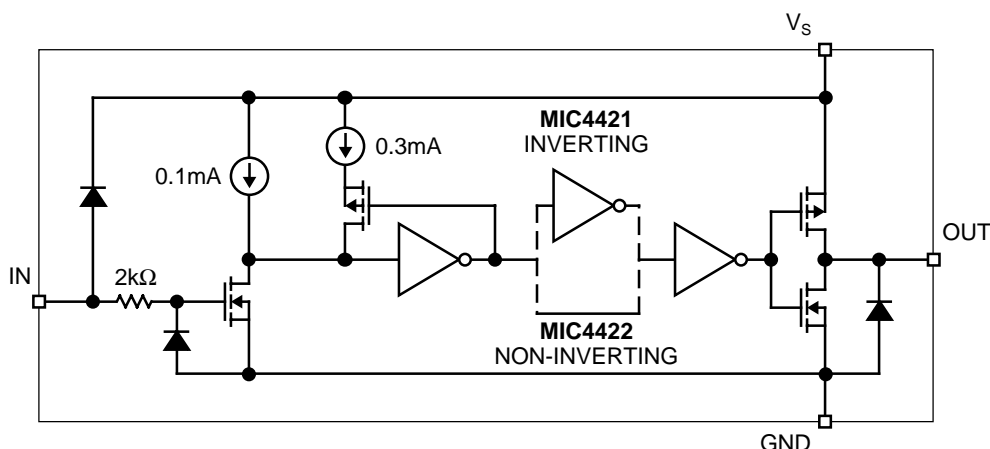
### Features

- BiCMOS/DMOS Construction
- Latch-Up Proof: Fully Isolated Process is Inherently Immune to Any Latch-up.
- Input Will Withstand Negative Swing of Up to 5V
- Matched Rise and Fall Times ..... 25ns
- High Peak Output Current ..... 9A Peak
- Wide Operating Range ..... 4.5V to 18V
- High Capacitive Load Drive ..... 47,000pF
- Low Delay Time ..... 30ns Typ.
- Logic High Input for Any Voltage from 2.4V to  $V_S$
- Low Equivalent Input Capacitance (typ) ..... 7pF
- Low Supply Current ..... 450 $\mu$ A With Logic 1 Input
- Low Output Impedance ..... 1.5 $\Omega$
- Output Voltage Swing to Within 25mV of GND or  $V_S$

### Applications

- Switch Mode Power Supplies
- Motor Controls
- Pulse Transformer Driver
- Class-D Switching Amplifiers
- Line Drivers
- Driving MOSFET or IGBT Parallel Chip Modules
- Local Power ON/OFF Switch
- Pulse Generators

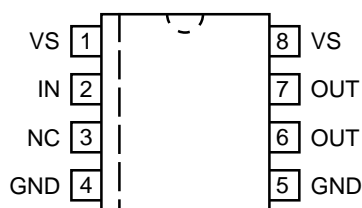
### Functional Diagram



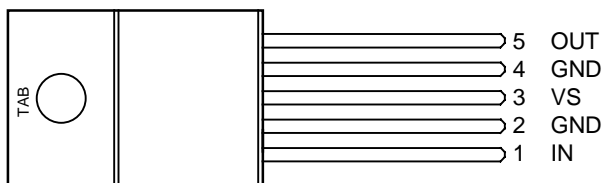
## Ordering Information

Part No.	Temperature Range	Package	Configuration
MIC4421CN	0°C to +70°C	8-Pin PDIP	Inverting
MIC4421BN	-40°C to +85°C	8-Pin PDIP	Inverting
MIC4421CM	0°C to +70°C	8-Pin SOIC	Inverting
MIC4421BM	-40°C to +85°C	8-Pin SOIC	Inverting
MIC4421CT	0°C to +70°C	5-Pin TO-220	Inverting
MIC4422CN	0°C to +70°C	8-Pin PDIP	Non-Inverting
MIC4422BN	-40°C to +85°C	8-Pin PDIP	Non-Inverting
MIC4422CM	0°C to +70°C	8-Pin SOIC	Non-Inverting
MIC4422BM	-40°C to +85°C	8-Pin SOIC	Non-Inverting
MIC4422CT	0°C to +70°C	5-Pin TO-220	Non-Inverting

## Pin Configurations



Plastic DIP (N)  
SOIC (M)



TO-220-5 (T)

## Pin Description

Pin Number TO-220-5	Pin Number DIP, SOIC	Pin Name	Pin Function
1	2	IN	Control Input
2, 4	4, 5	GND	Ground: Duplicate pins must be externally connected together.
3, TAB	1, 8	V <sub>S</sub>	Supply Input: Duplicate pins must be externally connected together.
5	6, 7	OUT	Output: Duplicate pins must be externally connected together.
	3	NC	Not connected.

**Absolute Maximum Ratings** (Notes 1, 2 and 3)

Supply Voltage .....	20V
Input Voltage .....	$V_S + 0.3V$ to GND – 5V
Input Current ( $V_{IN} > V_S$ ) .....	50 mA
Power Dissipation, $T_A \leq 25^\circ\text{C}$	
PDIP .....	960mW
SOIC .....	1040mW
5-Pin TO-220 .....	2W
Power Dissipation, $T_{CASE} \leq 25^\circ\text{C}$	
5-Pin TO-220 .....	12.5W
Derating Factors (to Ambient)	
PDIP .....	7.7mW/ $^\circ\text{C}$
SOIC .....	8.3mW/ $^\circ\text{C}$
5-Pin TO-220 .....	17mW/ $^\circ\text{C}$
Storage Temperature .....	$-65^\circ\text{C}$ to $+150^\circ\text{C}$
Lead Temperature (10 sec) .....	$300^\circ\text{C}$

**Operating Ratings**

Junction Temperature .....	$150^\circ\text{C}$
Ambient Temperature	
C Version .....	$0^\circ\text{C}$ to $+70^\circ\text{C}$
B Version .....	$-40^\circ\text{C}$ to $+85^\circ\text{C}$
Thermal Resistance	
5-Pin TO-220 ( $\theta_{JC}$ ) .....	$10^\circ\text{C/W}$

**Electrical Characteristics:** ( $T_A = 25^\circ\text{C}$  with  $4.5\text{ V} \leq V_S \leq 18\text{ V}$  unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
<b>INPUT</b>						
$V_{IH}$	Logic 1 Input Voltage		2.4	1.3		V
$V_{IL}$	Logic 0 Input Voltage			1.1	0.8	V
$V_{IN}$	Input Voltage Range		-5		$V_S+0.3$	V
$I_{IN}$	Input Current	$0\text{ V} \leq V_{IN} \leq V_S$	-10		10	$\mu\text{A}$
<b>OUTPUT</b>						
$V_{OH}$	High Output Voltage	See Figure 1	$V_S-0.025$			V
$V_{OL}$	Low Output Voltage	See Figure 1			0.025	V
$R_O$	Output Resistance, Output High	$I_{OUT} = 10\text{ mA}$ , $V_S = 18\text{ V}$		0.6		$\Omega$
$R_O$	Output Resistance, Output Low	$I_{OUT} = 10\text{ mA}$ , $V_S = 18\text{ V}$		0.8	1.7	$\Omega$
$I_{PK}$	Peak Output Current	$V_S = 18\text{ V}$ (See Figure 6)		9		A
$I_{DC}$	Continuous Output Current		2			A
$I_R$	Latch-Up Protection Withstand Reverse Current	Duty Cycle $\leq 2\%$ $t \leq 300\ \mu\text{s}$	>1500			mA
<b>SWITCHING TIME</b> (Note 3)						
$t_R$	Rise Time	Test Figure 1, $C_L = 10,000\text{ pF}$		20	75	ns
$t_F$	Fall Time	Test Figure 1, $C_L = 10,000\text{ pF}$		24	75	ns
$t_{D1}$	Delay Time	Test Figure 1		15	60	ns
$t_{D2}$	Delay Time	Test Figure 1		35	60	ns
<b>POWER SUPPLY</b>						
$I_S$	Power Supply Current	$V_{IN} = 3\text{ V}$ $V_{IN} = 0\text{ V}$		0.4 80	1.5 150	mA $\mu\text{A}$
$V_S$	Operating Input Voltage		4.5		18	V

**Electrical Characteristics:** (Over operating temperature range with  $4.5V \leq V_S \leq 18V$  unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
<b>INPUT</b>						
$V_{IH}$	Logic 1 Input Voltage		2.4	1.4		V
$V_{IL}$	Logic 0 Input Voltage			1.0	0.8	V
$V_{IN}$	Input Voltage Range		-5		$V_S+0.3$	V
$I_{IN}$	Input Current	$0V \leq V_{IN} \leq V_S$	-10		10	$\mu A$
<b>OUTPUT</b>						
$V_{OH}$	High Output Voltage	Figure 1	$V_S-.025$			V
$V_{OL}$	Low Output Voltage	Figure 1			0.025	V
$R_O$	Output Resistance, Output High	$I_{OUT} = 10mA, V_S = 18V$		0.8	3.6	$\Omega$
$R_O$	Output Resistance, Output Low	$I_{OUT} = 10mA, V_S = 18V$		1.3	2.7	$\Omega$

**SWITCHING TIME** (Note 3)

$t_R$	Rise Time	Figure 1, $C_L = 10,000pF$		23	120	ns
$t_F$	Fall Time	Figure 1, $C_L = 10,000pF$		30	120	ns
$t_{D1}$	Delay Time	Figure 1		20	80	ns
$t_{D2}$	Delay Time	Figure 1		40	80	ns

**POWER SUPPLY**

$I_S$	Power Supply Current	$V_{IN} = 3V$ $V_{IN} = 0V$		0.6 0.1	3 0.2	mA
$V_S$	Operating Input Voltage		4.5		18	V

**Note 1:** Functional operation above the absolute maximum stress ratings is not implied.

**Note 2:** Static-sensitive device. Store only in conductive containers. Handling personnel and equipment should be grounded to prevent damage from static discharge.

**Note 3:** Switching times guaranteed by design.

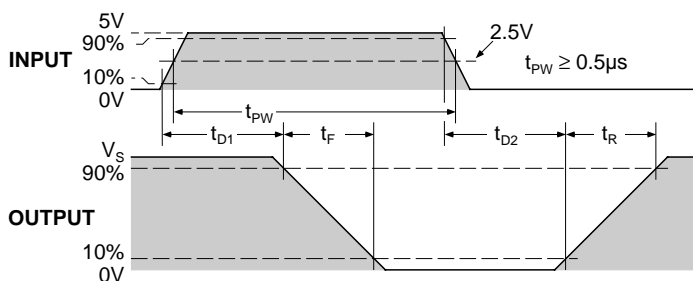
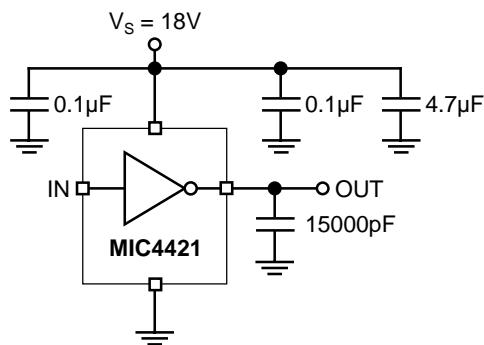
**Test Circuits**

Figure 1. Inverting Driver Switching Time

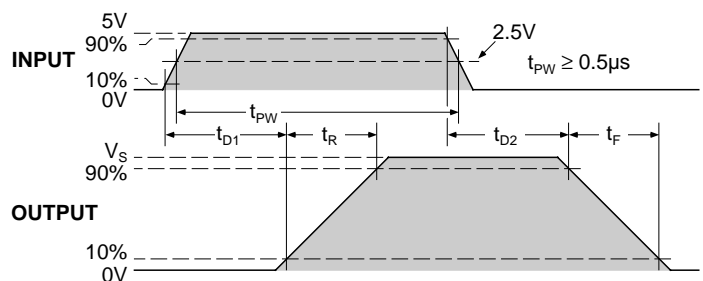
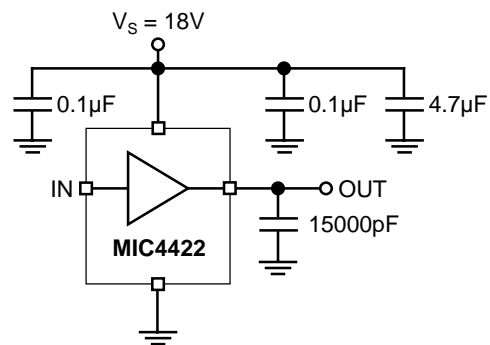
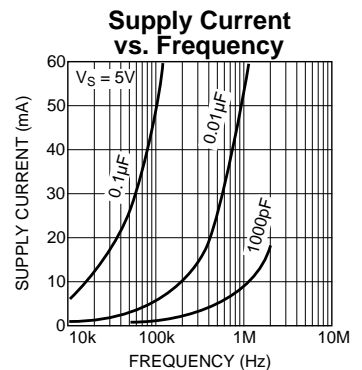
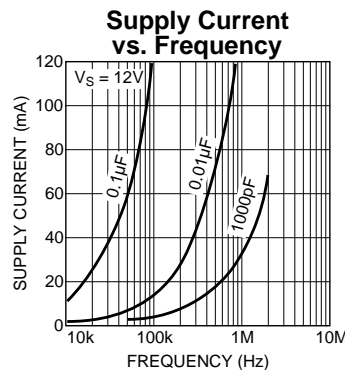
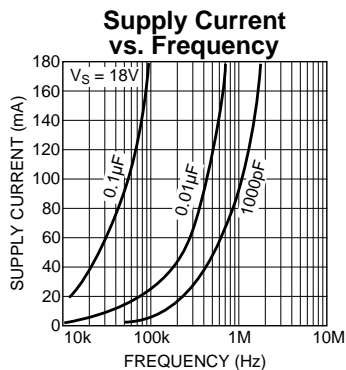
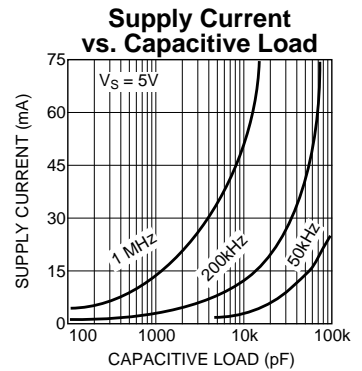
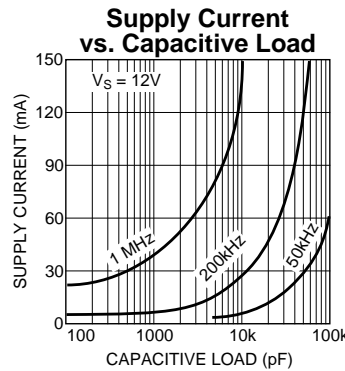
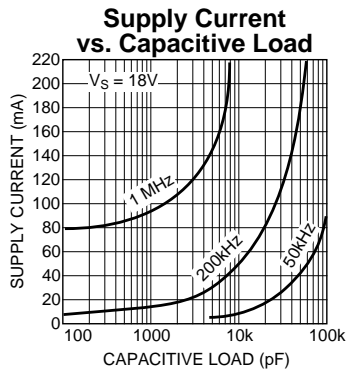
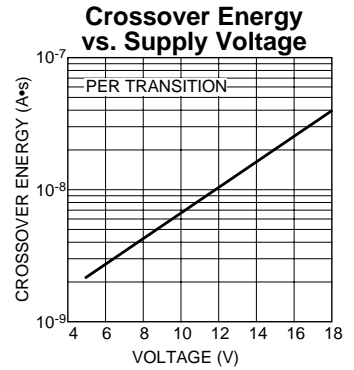
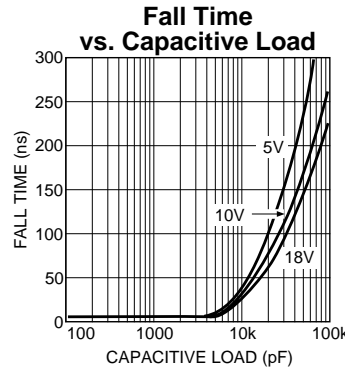
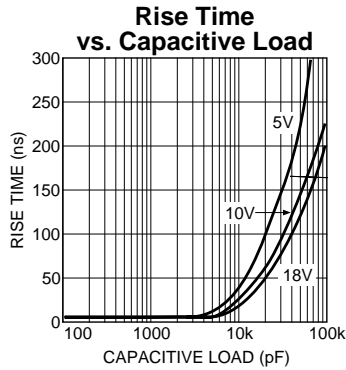
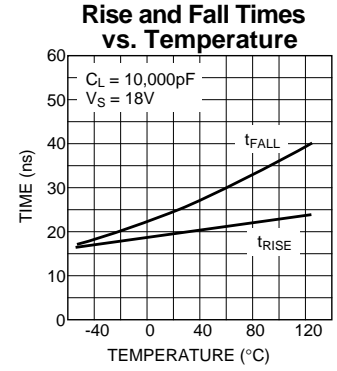
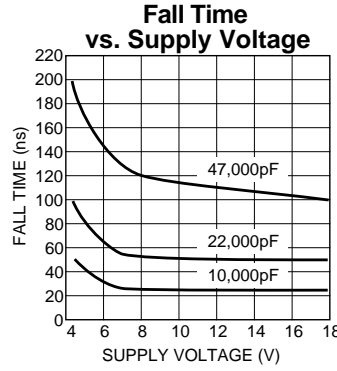
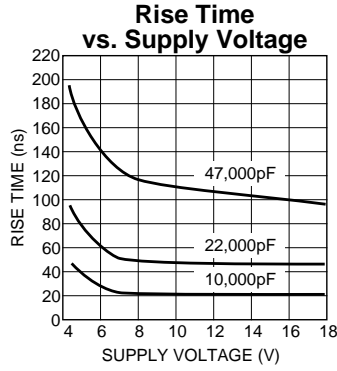
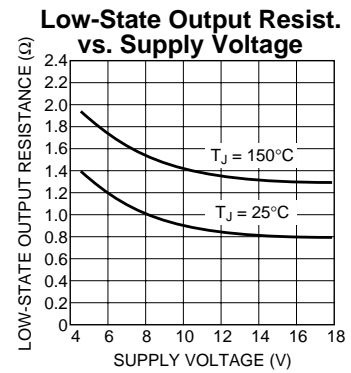
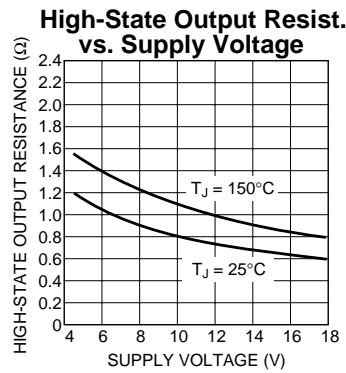
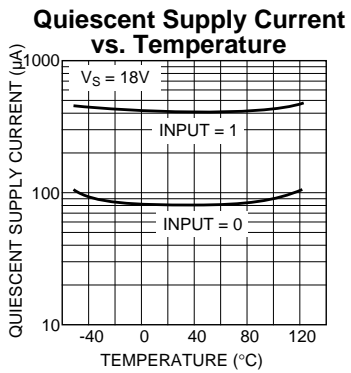
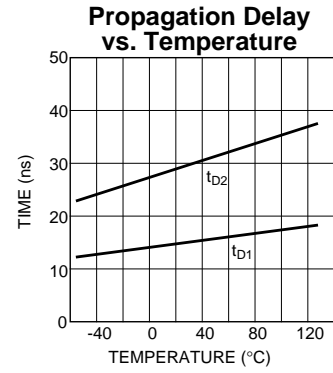
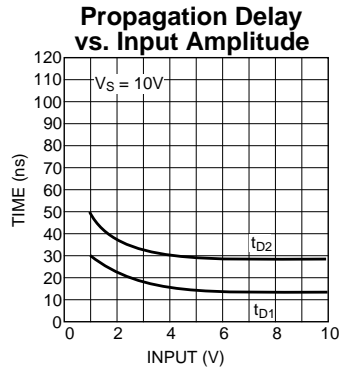
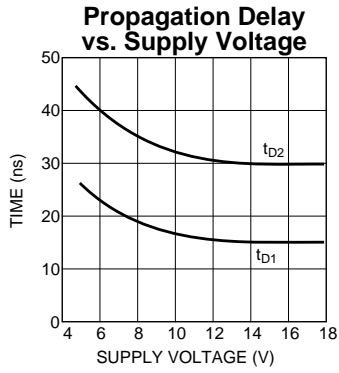


Figure 2. Noninverting Driver Switching Time

# Typical Characteristics



# Typical Characteristics



## Applications Information

### Supply Bypassing

Charging and discharging large capacitive loads quickly requires large currents. For example, charging a 10,000pF load to 18V in 50ns requires 3.6A.

The MIC4421/4422 has double bonding on the supply pins, the ground pins and output pins. This reduces parasitic lead inductance. Low inductance enables large currents to be switched rapidly. It also reduces internal ringing that can cause voltage breakdown when the driver is operated at or near the maximum rated voltage.

Internal ringing can also cause output oscillation due to feedback. This feedback is added to the input signal since it is referenced to the same ground.

To guarantee low supply impedance over a wide frequency range, a parallel capacitor combination is recommended for supply bypassing. Low inductance ceramic disk capacitors with short lead lengths (< 0.5 inch) should be used. A 1µF low ESR film capacitor in parallel with two 0.1µF low ESR ceramic capacitors, (such as AVX RAM Guard®), provides adequate bypassing. Connect one ceramic capacitor directly between pins 1 and 4. Connect the second ceramic capacitor directly between pins 8 and 5.

### Grounding

The high current capability of the MIC4421/4422 demands careful PC board layout for best performance. Since the MIC4421 is an inverting driver, any ground lead impedance will appear as negative feedback which can degrade switching speed. Feedback is especially noticeable with slow-rise time inputs. The MIC4421 input structure includes about 200mV of hysteresis to ensure clean transitions and freedom from oscillation, but attention to layout is still recommended.

Figure 5 shows the feedback effect in detail. As the MIC4421 input begins to go positive, the output goes negative and several amperes of current flow in the ground lead. As little as 0.05Ω of PC trace resistance can produce hundreds of millivolts at the MIC4421 ground pins. If the driving logic is referenced to power ground, the effective logic input level is reduced and oscillation may result.

To insure optimum performance, separate ground traces should be provided for the logic and power connections. Connecting the logic ground directly to the MIC4421 GND pins will ensure full logic drive to the input and ensure fast output switching. Both of the MIC4421 GND pins should, however, still be connected to power ground.

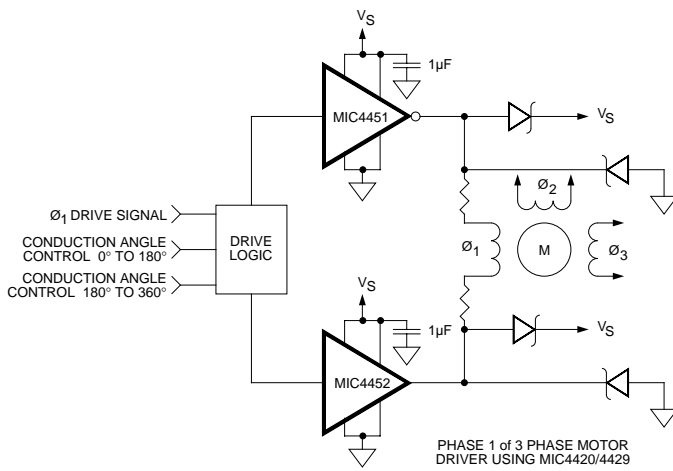


Figure 3. Direct Motor Drive

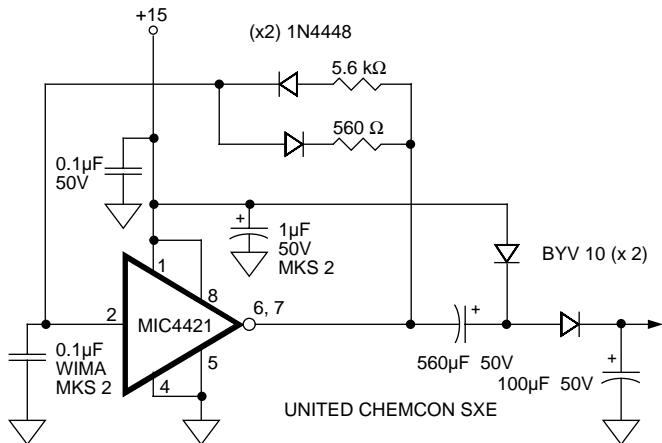
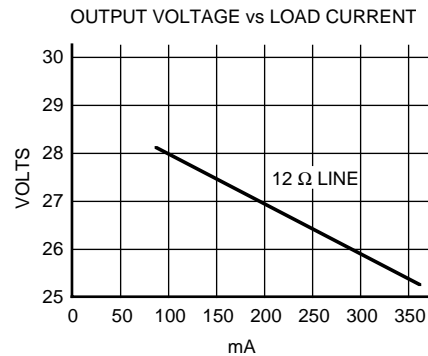


Figure 4. Self Contained Voltage Doubler







### Capacitive Load Power Dissipation

Dissipation caused by a capacitive load is simply the energy placed in, or removed from, the load capacitance by the driver. The energy stored in a capacitor is described by the equation:

$$E = 1/2 C V^2$$

As this energy is lost in the driver each time the load is charged or discharged, for power dissipation calculations the 1/2 is removed. This equation also shows that it is good practice not to place more voltage in the capacitor than is necessary, as dissipation increases as the square of the voltage applied to the capacitor. For a driver with a capacitive load:

$$P_L = f C (V_S)^2$$

where:

- f = Operating Frequency
- C = Load Capacitance
- V<sub>S</sub> = Driver Supply Voltage

### Inductive Load Power Dissipation

For inductive loads the situation is more complicated. For the part of the cycle in which the driver is actively forcing current into the inductor, the situation is the same as it is in the resistive case:

$$P_{L1} = I^2 R_O D$$

However, in this instance the R<sub>O</sub> required may be either the on resistance of the driver when its output is in the high state, or its on resistance when the driver is in the low state, depending on how the inductor is connected, and this is still only half the story. For the part of the cycle when the inductor is forcing current through the driver, dissipation is best described as

$$P_{L2} = I V_D (1 - D)$$

where V<sub>D</sub> is the forward drop of the clamp diode in the driver (generally around 0.7V). The two parts of the load dissipation must be summed in to produce P<sub>L</sub>

$$P_L = P_{L1} + P_{L2}$$

### Quiescent Power Dissipation

Quiescent power dissipation (P<sub>Q</sub>, as described in the input section) depends on whether the input is high or low. A low input will result in a maximum current drain (per driver) of ≤ 0.2mA; a logic high will result in a current drain of ≤ 3.0mA. Quiescent power can therefore be found from:

$$P_Q = V_S [D I_H + (1 - D) I_L]$$

where:

- I<sub>H</sub> = quiescent current with input high
- I<sub>L</sub> = quiescent current with input low
- D = fraction of time input is high (duty cycle)
- V<sub>S</sub> = power supply voltage

### Transition Power Dissipation

Transition power is dissipated in the driver each time its output changes state, because during the transition, for a very brief interval, both the N- and P-channel MOSFETs in the output totem-pole are ON simultaneously, and a current is conducted through them from V<sub>S</sub> to ground. The transition power dissipation is approximately:

$$P_T = 2 f V_S (A \bullet s)$$

where (A•s) is a time-current factor derived from the typical characteristic curve "Crossover Energy vs. Supply Voltage."

Total power (P<sub>D</sub>) then, as previously described is just

$$P_D = P_L + P_Q + P_T$$

### Definitions

- C<sub>L</sub> = Load Capacitance in Farads.
- D = Duty Cycle expressed as the fraction of time the input to the driver is high.
- f = Operating Frequency of the driver in Hertz
- I<sub>H</sub> = Power supply current drawn by a driver when both inputs are high and neither output is loaded.
- I<sub>L</sub> = Power supply current drawn by a driver when both inputs are low and neither output is loaded.
- I<sub>D</sub> = Output current from a driver in Amps.
- P<sub>D</sub> = Total power dissipated in a driver in Watts.
- P<sub>L</sub> = Power dissipated in the driver due to the driver's load in Watts.
- P<sub>Q</sub> = Power dissipated in a quiescent driver in Watts.
- P<sub>T</sub> = Power dissipated in a driver when the output changes states ("shoot-through current") in Watts. NOTE: The "shoot-through" current from a dual transition (once up, once down) for both drivers is stated in Figure 7 in ampere-nanoseconds. This figure must be multiplied by the number of repetitions per second (frequency) to find Watts.
- R<sub>O</sub> = Output resistance of a driver in Ohms.
- V<sub>S</sub> = Power supply voltage to the IC in Volts.

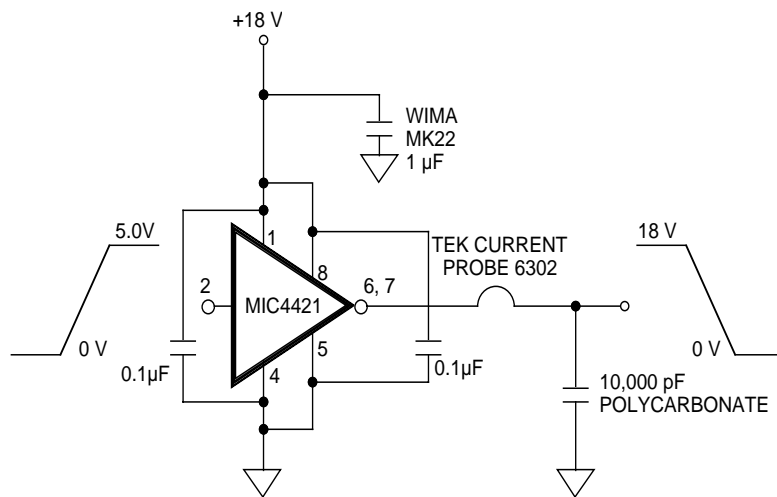
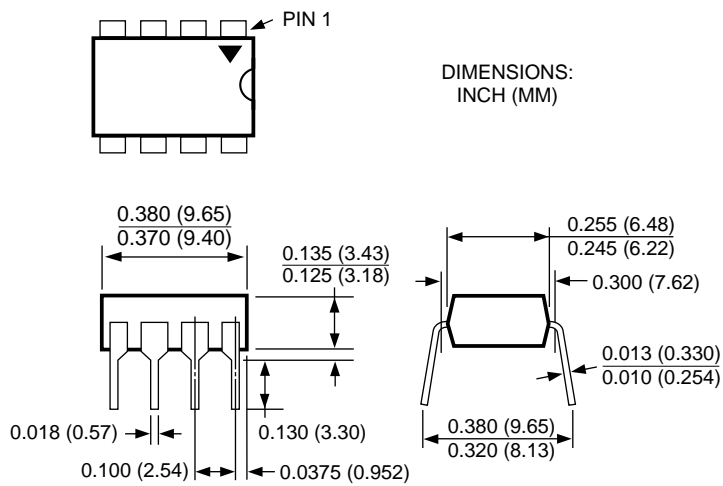
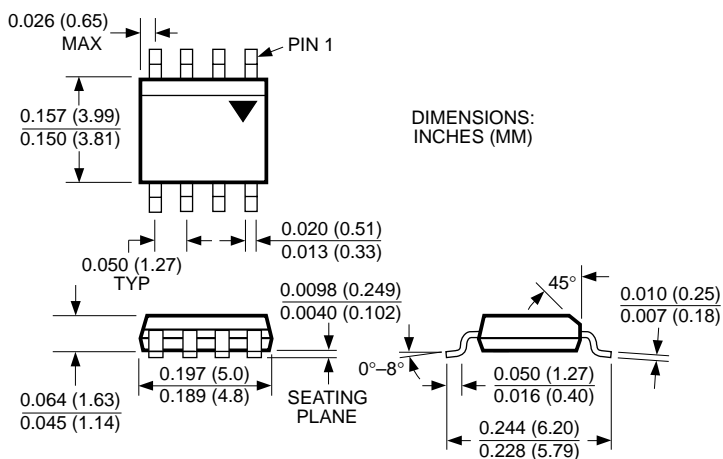


Figure 6. Peak Output Current Test Circuit

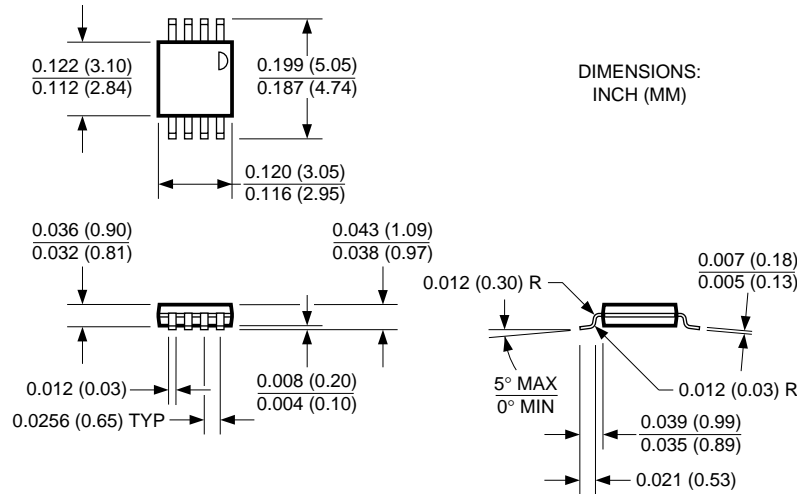
# Package Information



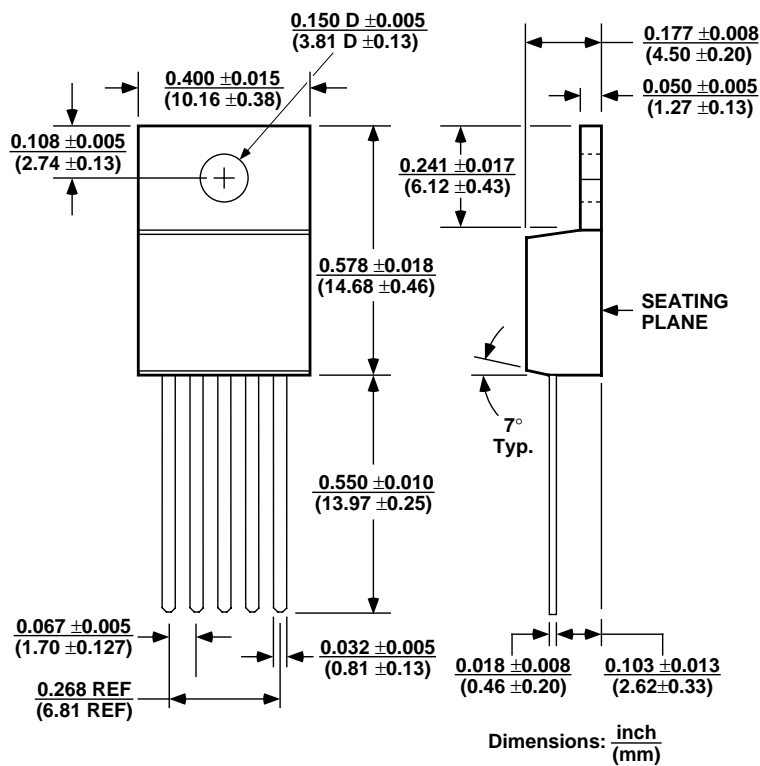
**8-Pin Plastic DIP (N)**



**8-Pin SOP (M)**



8-Pin MSOP (MM)



5-Lead TO-220 (T)

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